

PTFA080551E/F

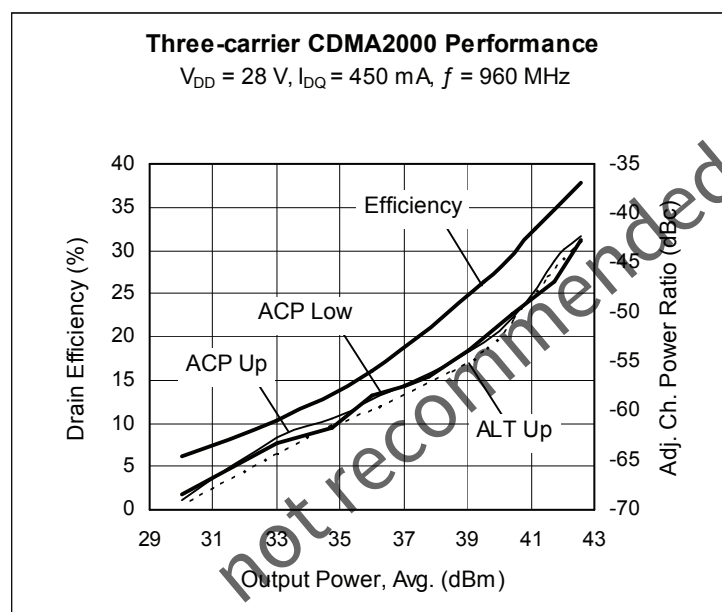
Thermally-Enhanced High Power RF LDMOS FETs 55 W, 869 – 960 MHz

Description

The PTFA080551E and PTFA080551F are 55-watt LDMOS FETs designed for EDGE and CDMA power amplifier applications in the 869 to 960 MHz band. Features include input matching and thermally-enhanced packages with slotted or earless flanges. Manufactured with Wolfspeed's advanced LDMOS process, these devices provide excellent thermal performance and superior reliability.

PTFA080551E
Package H-36265-2

PTFA080551F
Package H-37265-2



Features

- Broadband internal matching
- Typical EDGE performance
 - Average output power = 26 W
 - Gain = 18 dB
 - Efficiency = 44%
- Typical CW performance
 - Output power at P-1dB = 75 W
 - Gain = 17 dB
 - Efficiency = 67%
- Integrated ESD protection: Human Body Model, Class 2 (minimum)
- Excellent thermal stability, low HCI drift
- Capable of handling 10:1 VSWR @ 28 V, 55 W (CW) output power
- Pb-free and RoHS compliant

RF Characteristics

EDGE Measurements (not subject to production test—verified by design/characterization in Wolfspeed test fixture)

$V_{DD} = 28\text{ V}$, $I_{DQ} = 450\text{ mA}$, $P_{OUT} = 26\text{ W AVG}$, $f = 959.8\text{ MHz}$

Characteristic	Symbol	Min	Typ	Max	Unit
Error Vector Magnitude	EVM (RMS)	—	2.5	—	%
Modulation Spectrum @ 400 kHz	ACPR	—	-60	—	dBc
Modulation Spectrum @ 600 kHz	ACPR	—	-75	—	dBc
Gain	G_{ps}	—	18	—	dB
Drain Efficiency	η_D	—	44	—	%

All published data at $T_{CASE} = 25^\circ\text{C}$ unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!

RF Characteristics (cont.)**Two-tone Measurements** (tested in WolfSpeed test fixture)
 $V_{DD} = 28\text{ V}$, $I_{DQ} = 600\text{ mA}$, $P_{OUT} = 55\text{ W PEP}$, $f = 960\text{ MHz}$, tone spacing = 1 MHz

Characteristic	Symbol	Min	Typ	Max	Unit
Gain	G_{ps}	18	18.5	—	dB
Drain Efficiency	η_D	46.5	48	—	%
Intermodulation Distortion	IMD	—	-31	-29	dBc

DC Characteristics

Characteristic	Conditions	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}$, $I_{DS} = 10\text{ }\mu\text{A}$	$V_{(BR)DSS}$	65	—	—	V
Drain Leakage Current	$V_{DS} = 28\text{ V}$, $V_{GS} = 0\text{ V}$	I_{DSS}	—	—	1.0	μA
	$V_{DS} = 63\text{ V}$, $V_{GS} = 0\text{ V}$	I_{DSS}	—	—	10.0	μA
On-State Resistance	$V_{GS} = 10\text{ V}$, $V_{DS} = 0.1\text{ V}$	$R_{DS(on)}$	—	0.15	—	Ω
Operating Gate Voltage	$V_{DS} = 28\text{ V}$, $I_{DQ} = 450\text{ mA}$	V_{GS}	2.0	2.3	3.0	V
Gate Leakage Current	$V_{GS} = 10\text{ V}$, $V_{DS} = 0\text{ V}$	I_{GSS}	—	—	1.0	μA

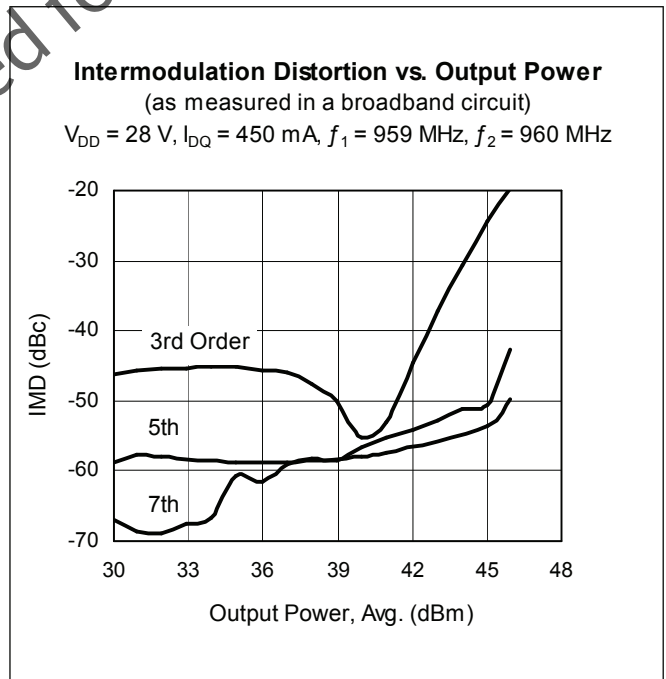
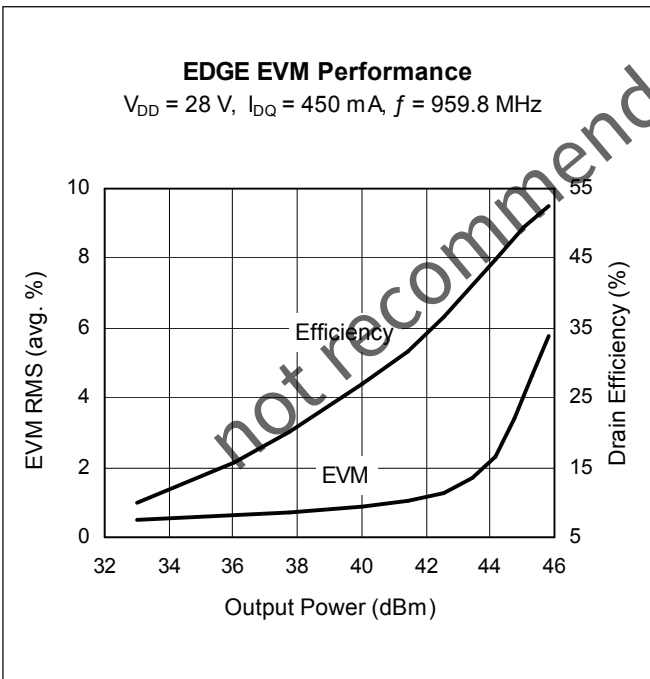
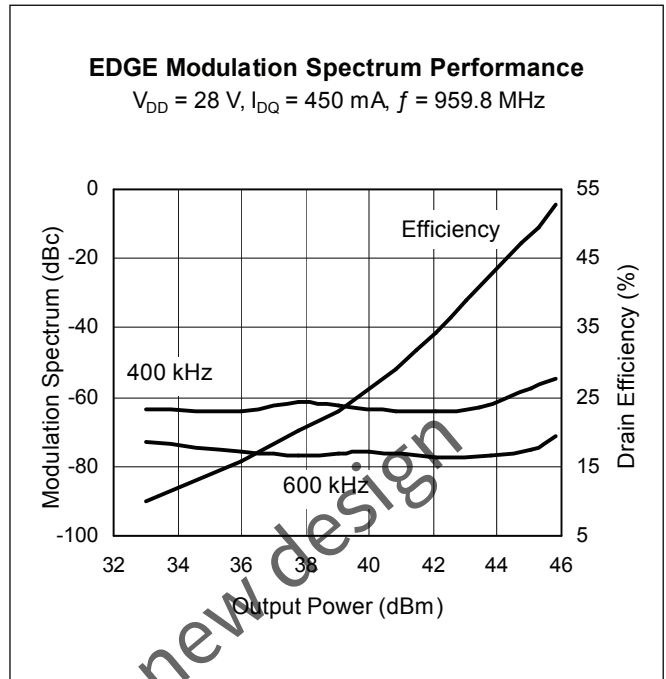
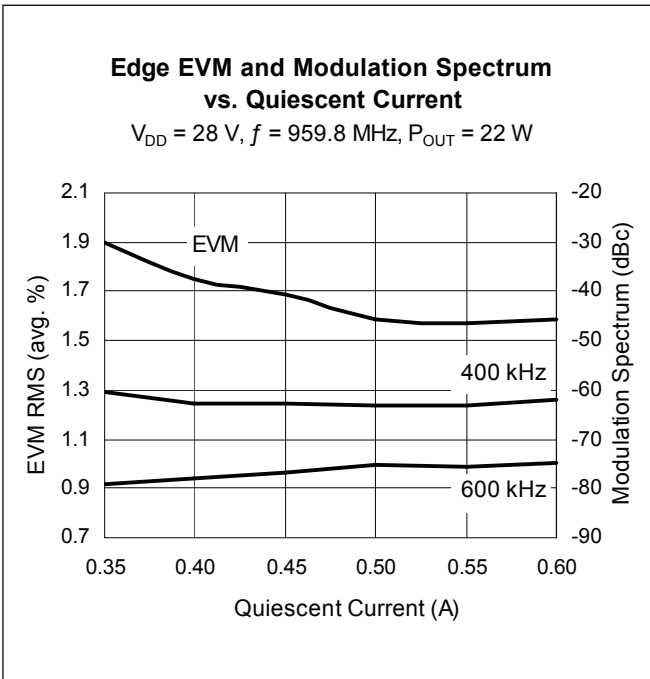
Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	65	V
Gate-Source Voltage	V_{GS}	-0.5 to +12	V
Junction Temperature	T_J	200	$^{\circ}\text{C}$
Total Device Dissipation	P_D	219	W
Above 25 $^{\circ}\text{C}$ derate by		1.25	W/ $^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-40 to +150	$^{\circ}\text{C}$
Thermal Resistance ($T_{CASE} = 70^{\circ}\text{C}$)	$R_{\theta JC}$	0.8	$^{\circ}\text{C/W}$

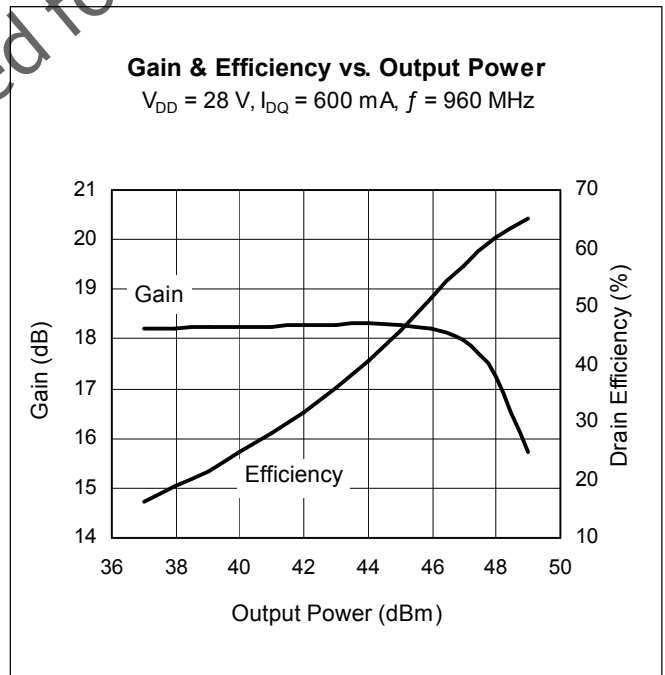
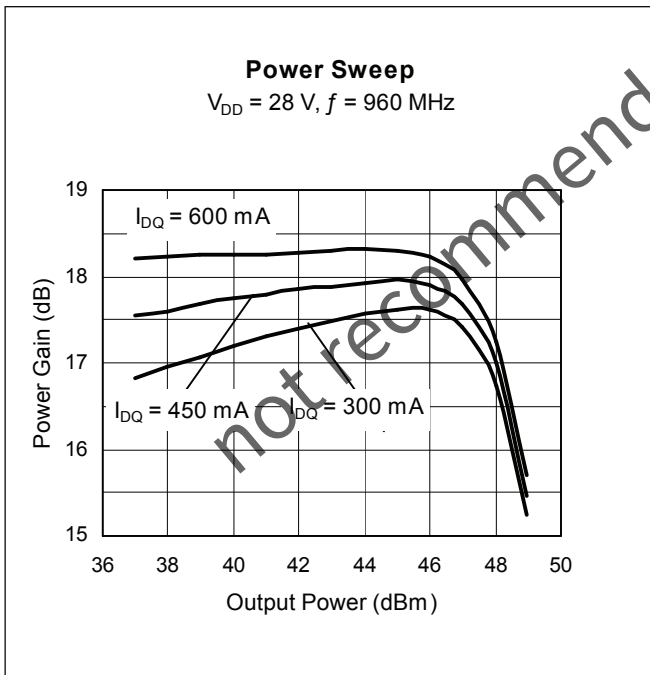
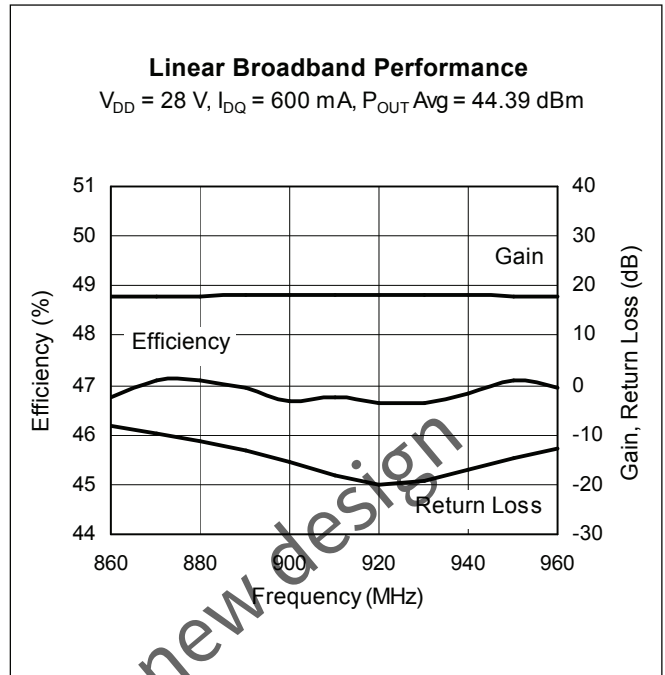
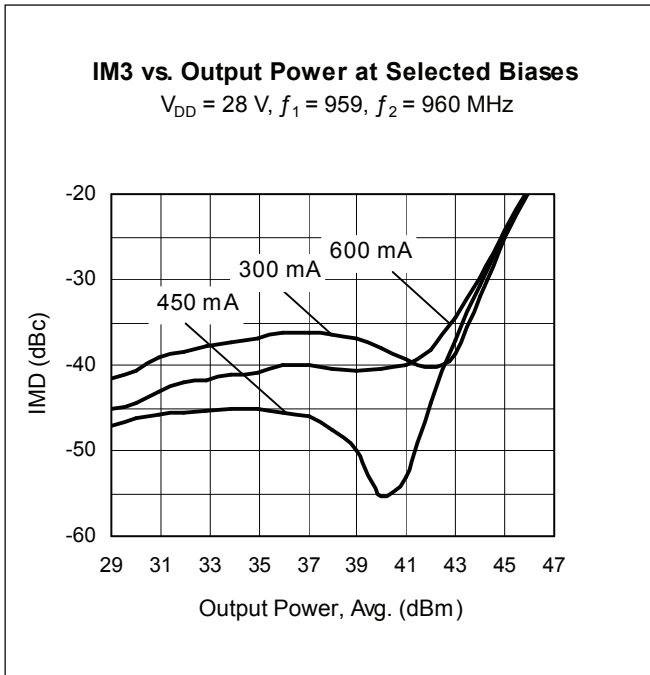
Ordering Information

Type and Version	Order Code	Package Description	Shipping
PTFA080551E V4 R0	PTFA080551E-V4-R0	H-36265-2, bolt-down	Tape & Reel, 50 pcs
PTFA080551E V4 R250	PTFA080551E-V4-R250	H-36265-2, bolt-down	Tape & Reel, 250 pcs
PTFA080551F V4 R0	PTFA080551F-V4-R0	H-37265-2, earless flange	Tape & Reel, 50 pcs
PTFA080551F V4 R250	PTFA080551F-V4-R250	H-37265-2, earless flange	Tape & Reel, 250 pcs

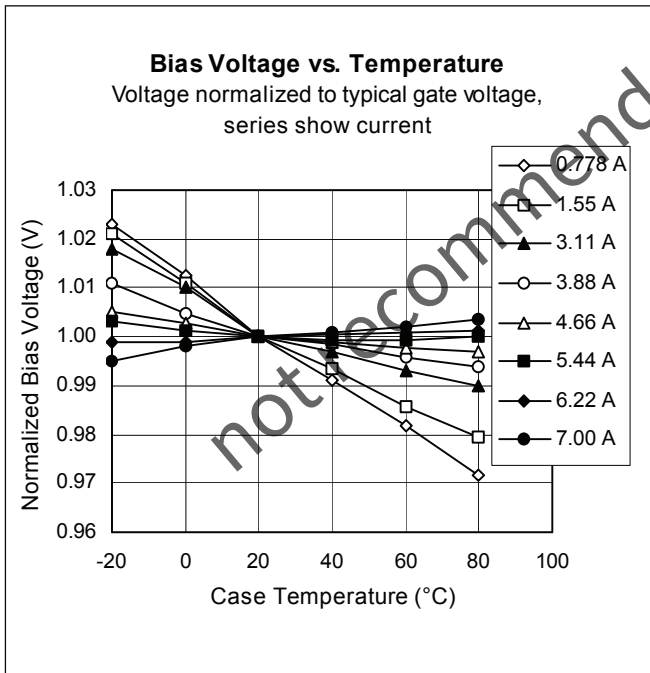
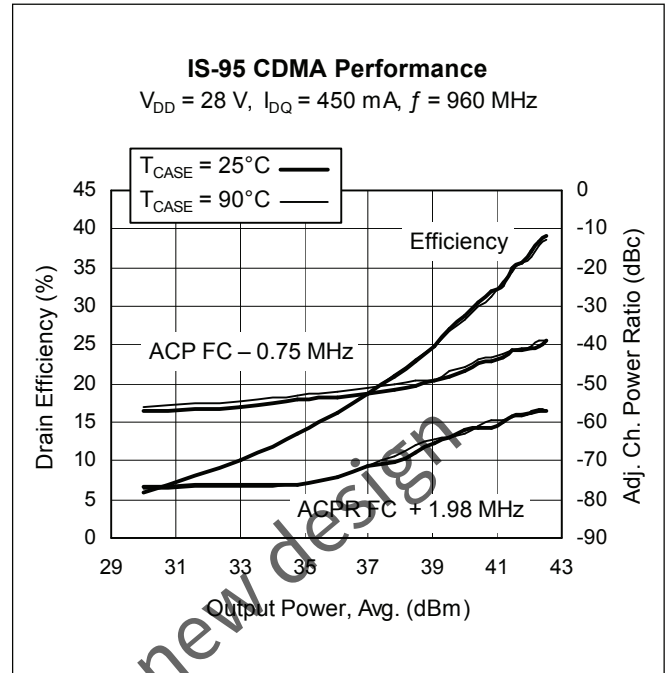
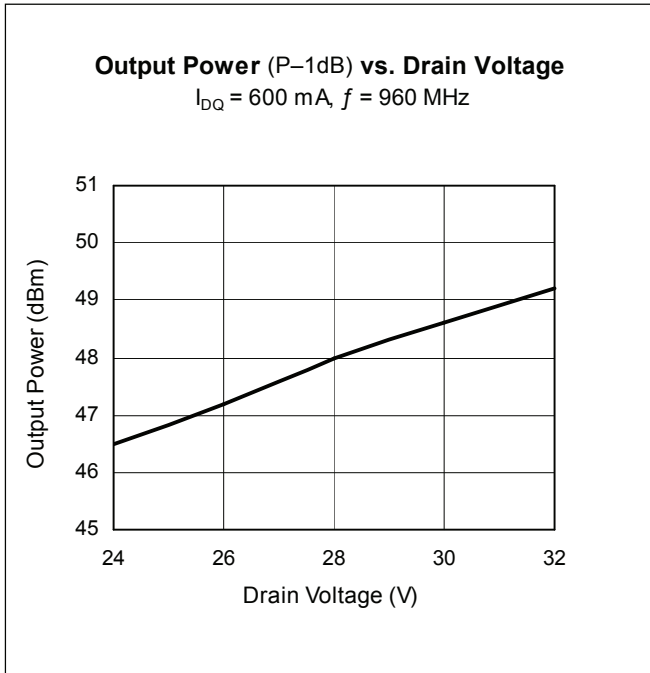
Typical Performance (data taken in a production test fixture)



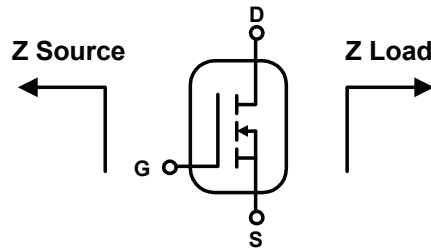
Typical Performance (cont.)



Typical Performance (cont.)



Broadband Circuit Impedance

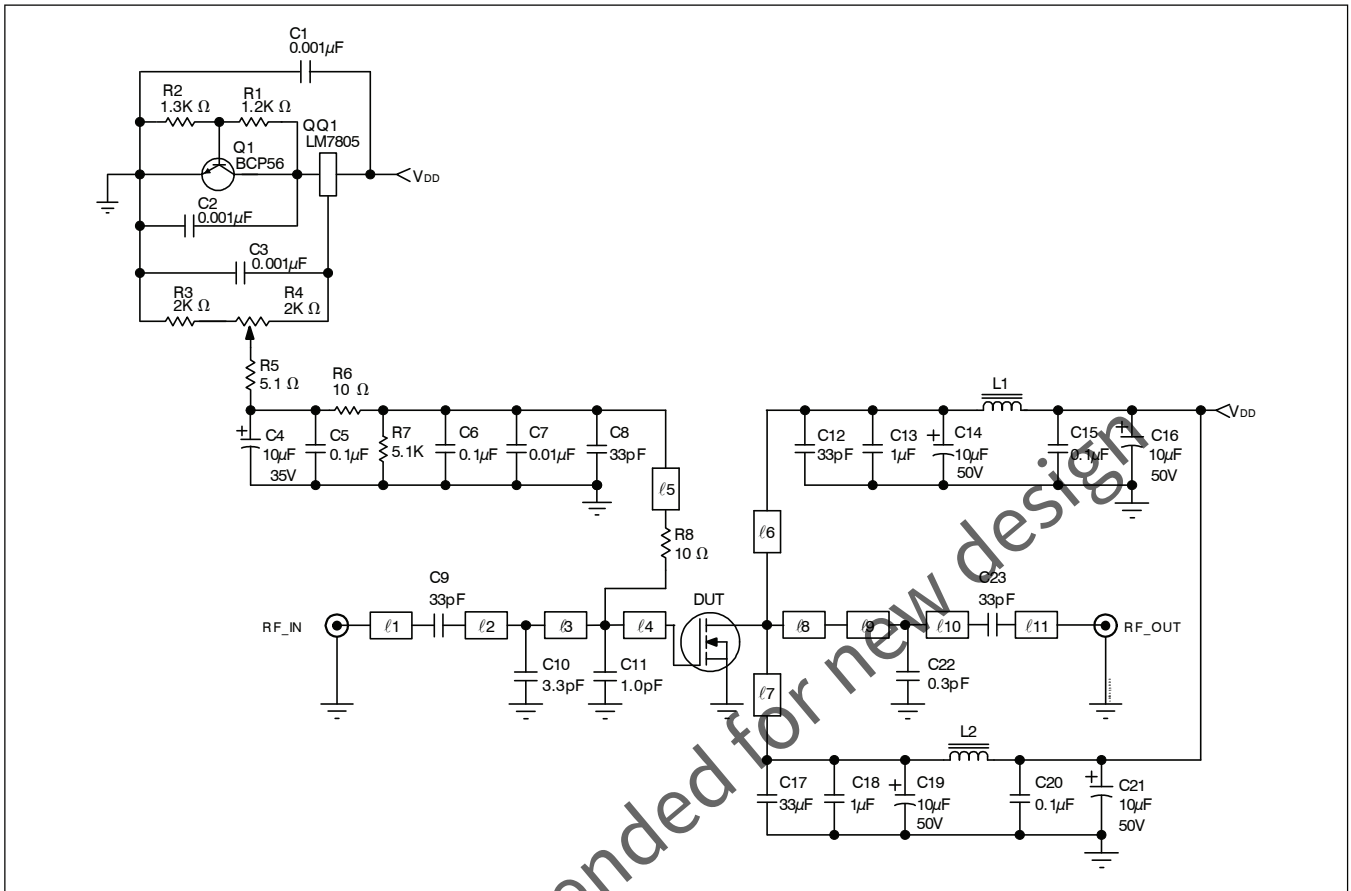


Frequency	Z Source		Z Load	
	R	jX	R	jX
869	8.91	-10.93	7.42	-1.63
880	3.72	-8.28	4.65	-1.74
894	5.93	-5.43	4.61	0.16
920	4.87	-7.16	4.88	0.59
960	6.05	-5.57	4.89	0.86

See next page for circuit information

not recommended for new design

Reference Circuit



Reference circuit schematic diagram for $f = 960 \text{ MHz}$

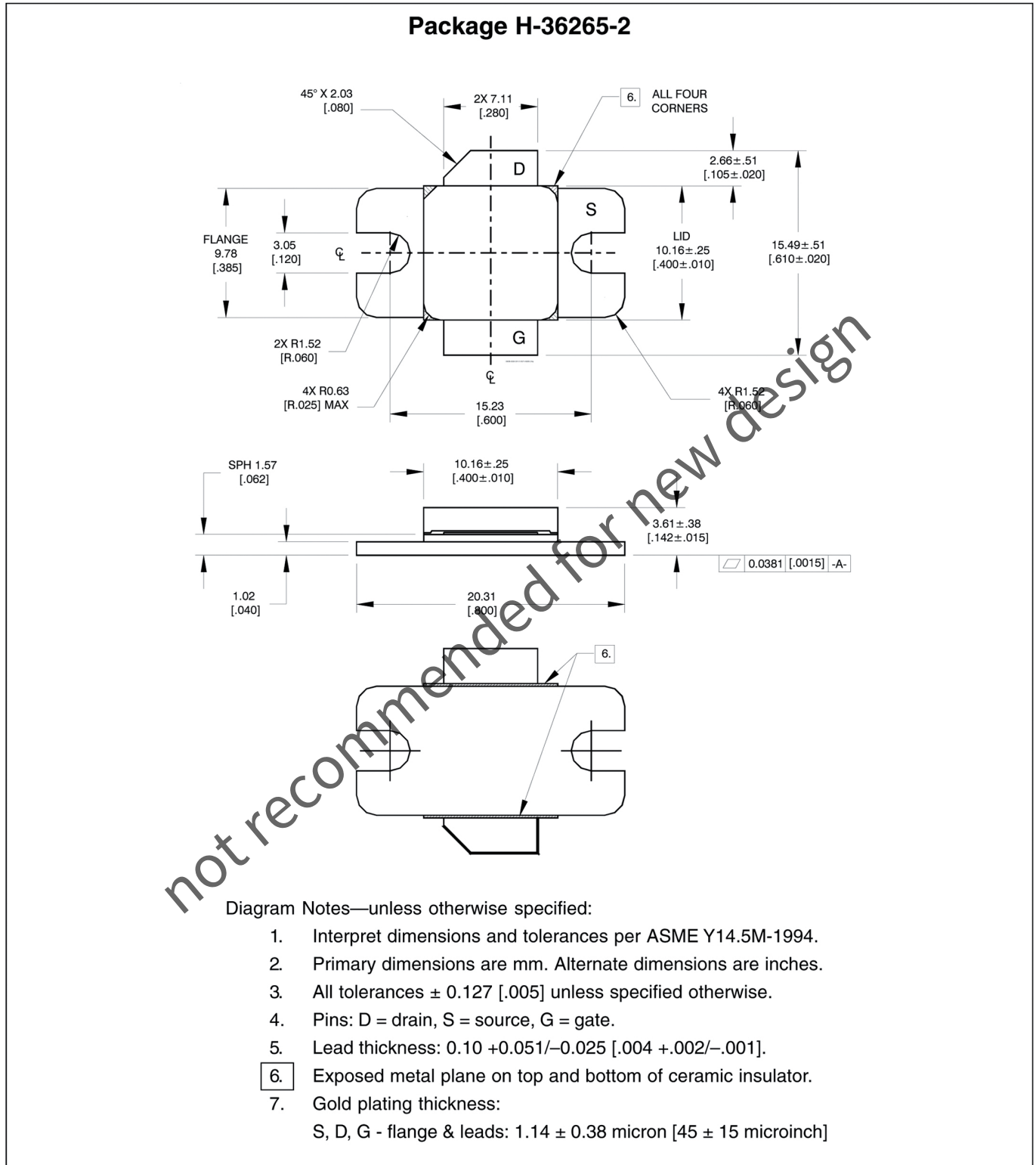
Circuit Assembly Information

DUT	PTFA080551E or PTFA080551F	LDMOS Transistor	
PCB	0.76 mm [.030"] thick, $\epsilon_r = 4.5$	Rogers TMM4	2 oz. copper

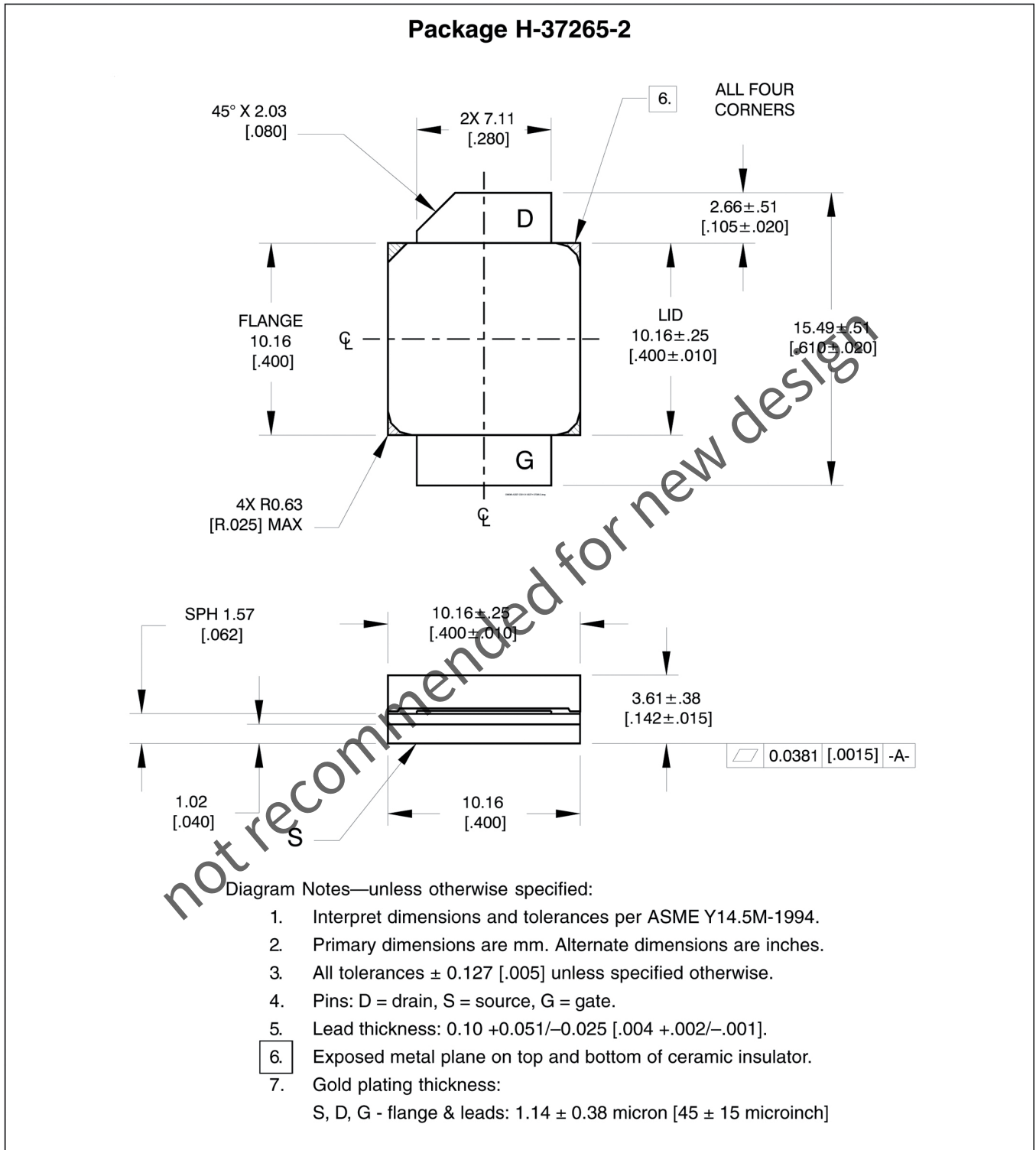
Microstrip	Electrical Characteristics at 960 MHz ¹	Dimensions: L x W (mm)	Dimensions: L x W (in.)
l_1	$0.070 \lambda, 50.0 \Omega$	12.19 x 1.37	0.480 x 0.054
l_2	$0.122 \lambda, 50.0 \Omega$	20.93 x 1.37	0.824 x 0.054
l_3	$0.031 \lambda, 50.0 \Omega$	5.31 x 1.37	0.209 x 0.054
l_4	$0.063 \lambda, 7.5 \Omega$	9.58 x 16.21	0.377 x 0.638
l_5	$0.162 \lambda, 67.0 \Omega$	28.45 x 0.79	1.120 x 0.031
l_6, l_7	$0.150 \lambda, 55.0 \Omega$	25.65 x 1.17	1.010 x 0.046
l_8	$0.198 \lambda, 11.1 \Omega$	30.73 x 10.46	1.210 x 0.412
l_9	$0.145 \lambda, 38.0 \Omega$	24.21 x 2.16	0.953 x 0.085
l_{10}	$0.009 \lambda, 38.0 \Omega$	1.52 x 2.16	0.060 x 0.085
l_{11}	$0.026 \lambda, 50.0 \Omega$	4.50 x 1.37	0.177 x 0.054

¹Electrical characteristics are rounded.

Package Outline Specifications



Package Outline Specifications (cont.)



Revision History

Revision	Date	Data Sheet Type	Page	Subjects (major changes since last revision)
05	2018-02-22	Data Sheet	All	Product discontinued
06	2018-08-09	Production	All	Converted to Wolfspeed data sheet, not recommended for new design

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Notes

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